1 Absolute maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	100 V	
V _{CEO}	Collector-emitter voltage (I _B = 0)	100 V	
V _{EBO}	Emitter-base voltage (I _C = 0)	5	V
I _C	Collector current	2	Α
I _{CM}	Collector peak current	4	Α
I _B	Base current	0.05	Α
P _{TOT}	Total dissipation at T _{case} = 25 °C	20	W
T _{STG}	Storage temperature	-65 to 150	°C
TJ	Max. operating junction temperature	150	°C

Note: For PNP types voltage and current values are negative.

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thJC}	Thermal resistance junction-case max.	6.25	°C/W

2 Electrical characteristics

 T_{case} = 25 °C; unless otherwise specified.

Table 4. Electrical characteristics

Symbol	Parameter	Test cor	nditions	Min.	Тур.	Max.	Unit
I _{CEV}	Collector cut-off current (V _{BE} = -1.5 V)	V _{CE} = 80 V V _{CE} = 80 V, T	c = 125 °C		-	10 0.5	μA mA
I _{CBO}	Collector cut-off current (I _E = 0)	V _{CB} = 80 V V _{CB} = 100 V			1	10 20	μΑ
I _{CEO}	Collector cut-off current (I _B = 0)	V _{CE} = 50 V			ı	20	μΑ
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = 5 V			1	2	mA
V _{CEO(sus)} ⁽¹⁾	Collector-emitter sustaining voltage (I _B = 0)	I _C = 30 mA		100	1		٧
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	I _C = 2 A	$I_B = 8 \text{ mA}$		1	2	V
VCE(sat)		I _C = 4 A	$I_B = 40 \text{ mA}$		1	3	٧
V _{BE(sat)} ⁽¹⁾	Base-emitter saturation voltage	I _C = 4 A	I _B = 40 mA		1	4	>
V _{BE(on)}	Base-emitter on voltage	I _C = 2 A	$V_{CE} = 3 V$		-	2.8	V
		$I_C = 0.5 A$	$V_{CE} = 3 V$	500	-		
h _{FE} ⁽¹⁾	DC current gain	I _C = 2 A	$V_{CE} = 3 V$	1000	-	12000	
		I _C = 4 A	$V_{CE} = 3 V$	200	-		
f _T	Transition frequency	I _C = 0.75 A f = 1 MHz	V _{CE} = 10 V	25	-		MHz
C _{CBO}	Collector base capacitance $(I_E = 0)$	V _{CB} = 10 V for MJD112 for MJD117	f = 0.1 MHz		-	100 200	pF pF

^{1.} Pulse test: pulse duration \leq 300 μ s, duty cycle \leq 2 %

Note: For PNP types voltage and current values are negative.

2.1 Typical characteristic (curves)

Figure 2. DC current gain

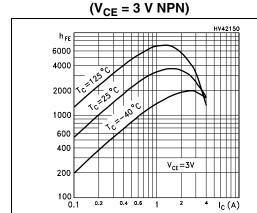


Figure 3. DC current gain $(V_{CE} = -3 \text{ V PNP})$

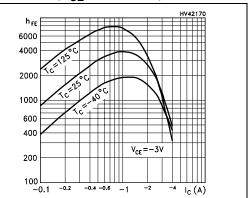


Figure 4. DC current gain (V_{CE} = 5 V NPN)

Figure 5. DC current gain $(V_{CE} = -5 \text{ V PNP})$

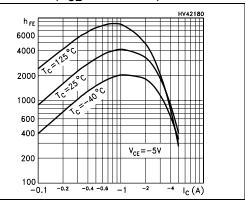


Figure 6. Collector-emitter saturation voltage (NPN)

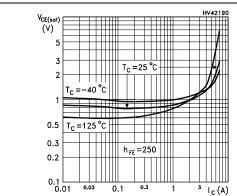


Figure 7. Collector-emitter saturation voltage (PNP)

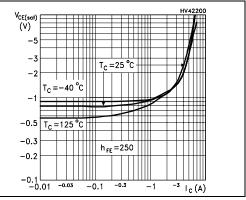
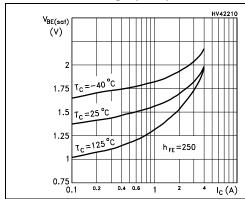


Figure 8. Base-emitter saturation voltage (NPN)

Figure 9. Base-emitter saturation voltage (PNP)



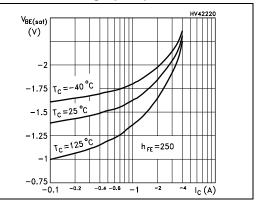
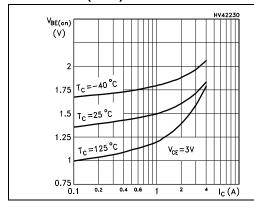


Figure 10. Base-emitter on voltage (NPN)

Figure 11. Base-emitter on voltage (PNP)



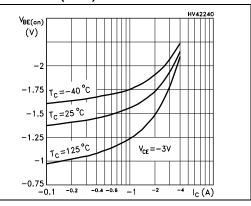
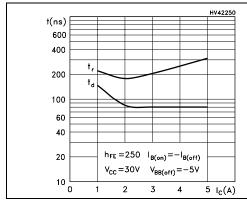
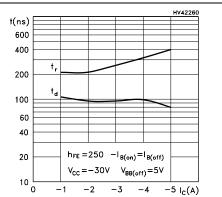


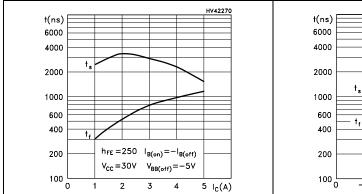
Figure 12. Resistive load switching time Figure 13. Resistive load switching time (NPN, on) (PNP, on)

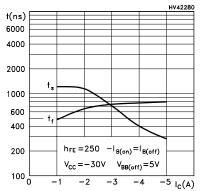




Electrical characteristics MJD112, MJD117

Figure 14. Resistive load switching time Figure 15. Resistive load switching time (NPN, off) (PNP, off)





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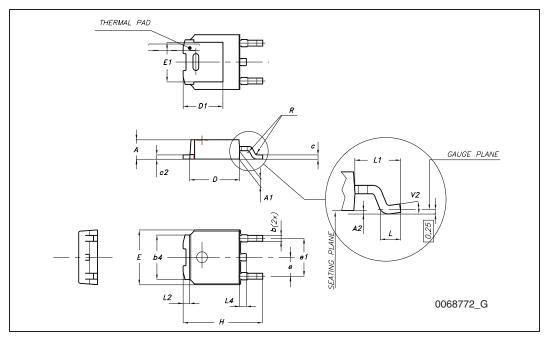
3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.



TO-252 (DP/	AK) mechanica	l data
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DIM.		mm.	
DIIVI.	min.	typ	max.
A	2.20		2.40
A1	0.90		1.10
A2	0.03		0.23
b	0.64		0.90
b4	5.20		5.40
С	0.45		0.60
c2	0.48		0.60
D	6.00		6.20
D1		5.10	
E	6.40		6.60
E1		4.70	
е		2.28	
e1	4.40		4.60
Н	9.35		10.10
L	1		
L1		2.80	
L2		0.80	
L4	0.60		1
R		0.20	
V2	0 °		8 °



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MJD112, MJD117 Revision history

4 Revision history

Table 5. Document revision history

Date	Revision	Changes
21-Jun-2004	2	Document migration, no content change.
21-Jan-2010	3	Modified TO-252 (DPAK) mechanical data.

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